

LM2902, LM324/LM324A, LM224/ LM224A

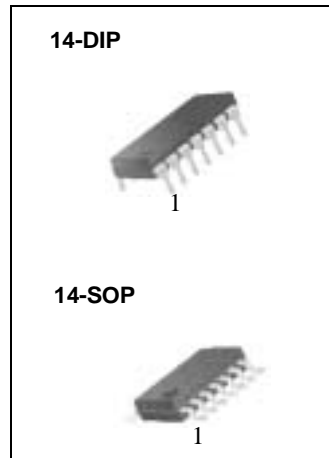
Quad Operational Amplifier

Features

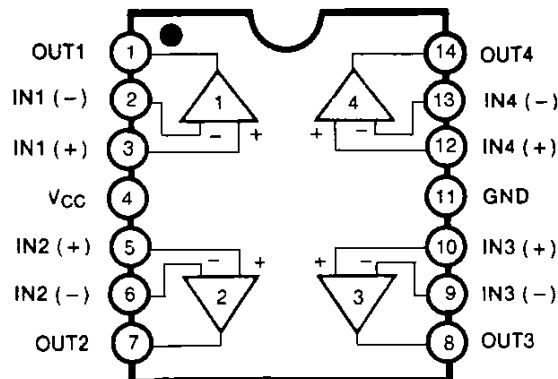
- Internally frequency compensated for unity gain
- Large DC voltage gain: 100dB
- Wide power supply range:
LM224/LM224A, LM324/LM324A : 3V~32V (or $\pm 1.5 \sim 15V$)
LM2902: 3V~26V (or $\pm 1.5V \sim 13V$)
- Input common mode voltage range includes ground
- Large output voltage swing: 0V to $V_{CC} - 1.5V$
- Power drain suitable for battery operation

Description

The LM324/LM324A, LM2902, LM224/LM224A consist of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide voltage range. Operation from split power supplies is also possible so long as the difference between the two supplies is 3 volts to 32 volts. Application areas include transducer amplifier, DC gain blocks and all the conventional OP amp circuits which now can be easily implemented in single power supply systems.

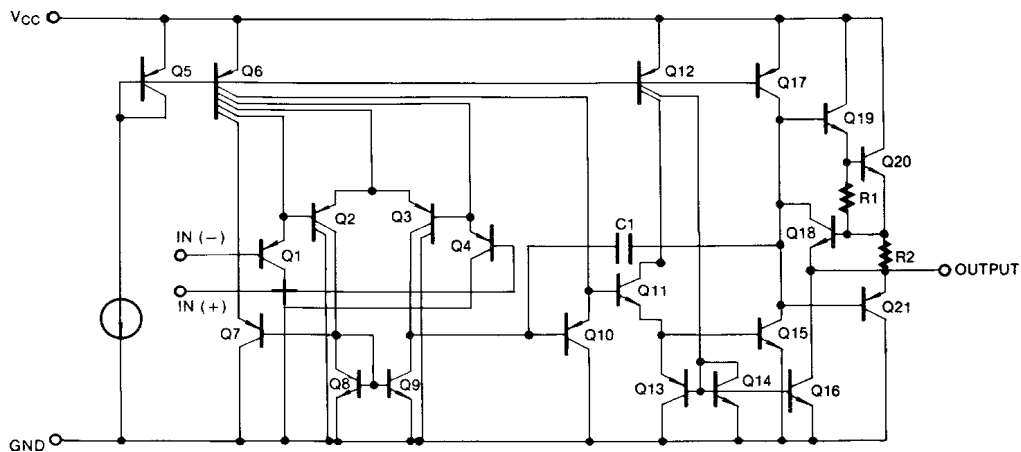


Internal Block Diagram



Schematic Diagram

(One Section Only)



Absolute Maximum Ratings

Parameter	Symbol	LM224/LM224A	LM324/LM324A	LM2902	Unit
Power Supply Voltage	V _{CC}	±16 or 32	±16 or 32	±13 or 26	V
Differential Input Voltage	V _{I(DIFF)}	32	32	26	V
Input Voltage	V _I	-0.3 to +32	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND V _{CC} ≤ 15V, T _A = 25°C (one Amp)	-	Continuous	Continuous	Continuous	-
Power Dissipation	P _D	570	570	570	mW
Operating Temperature Range	T _{OPR}	-25 ~ +85	0 ~ +70	-40 ~ +85	°C
Storage Temperature Range	T _{STG}	-65 ~ +150	-65 ~ +150	-65 ~ +150	°C

Electrical Characteristics

($V_{CC}=5.0V$, $V_{EE}=GND$, $T_A=25\text{ }^\circ\text{C}$, unless otherwise specified)

Parameter	Symbol	Conditions	LM224			LM324			LM2902			Unit	
			Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.		
Input Offset Voltage	V_{IO}	$V_{CM} = 0V$ to $V_{CC} - 1.5V$ $V_{O(P)} = 1.4V$, $R_S = 0\Omega$	-	1.5	5.0	-	1.5	7.0	-	1.5	7.0	mV	
Input Offset Current	I_{IO}	-	-	2.0	30	-	3.0	50	-	3.0	50	nA	
Input Bias Current	I_{BIAS}	-	-	40	150	-	40	250	-	40	250	nA	
Common-Mode Input Voltage Range	$V_{I(R)}$	Note1	0	-	$V_{CC} - 1.5$	0	$V_{CC} - 1.5$	-	0	-	$V_{CC} - 1.5$	V	
Supply Current	I_{CC}	$R_L = \infty$, $V_{CC} = 30V$ (all Amps)	-	1.0	3	-	1.0	3	-	1.0	3	mA	
		$R_L = \infty$, $V_{CC} = 5V$ (all Amps) ($V_{CC} = 26V$ for LM2902)	-	0.7	1.2	-	0.7	1.2	-	0.7	1.2	mA	
Large Signal Voltage Gain	G_V	$V_{CC} = 15V$, $R_L \geq 2K\Omega$ $V_{O(P)} = 1V$ to $11V$	50	100	-	25	100	-	-	100	-	V/ mV	
Output Voltage Swing	$V_{O(H)}$	Note1	$R_L = 2K\Omega$	26	-	-	26	-	-	22	-	-	V
			$R_L = 10K\Omega$	27	28	-	27	28	-	23	24	-	V
	$V_{O(L)}$	$V_{CC} = 5V$, $R_L \geq 10K\Omega$	-	5	20	-	5	20	-	5	100	mV	
Common-Mode Rejection Ratio	CMRR	-	70	85	-	65	75	-	50	75	-	dB	
Power Supply Rejection Ratio	PSRR	-	65	100	-	65	100	-	50	100	-	dB	
Channel Separation	CS	$f = 1KHz$ to $20KHz$	-	120	-	-	120	-	-	120	-	dB	
Short Circuit to GND	I_{SC}	-	-	40	60	-	40	60	-	40	60	mA	
Output Current	I_{SOURCE}	$V_{I(+)} = 1V$, $V_{I(-)} = 0V$ $V_{CC} = 15V$, $V_{O(P)} = 2V$	20	40	-	20	40	-	20	40	-	mA	
	I_{SINK}	$V_{I(+)} = 0V$, $V_{I(-)} = 1V$ $V_{CC} = 15V$, $V_{O(P)} = 2V$	10	13	-	10	13	-	10	13	-	mA	
		$V_{I(+)} = 0V$, $V_{I(-)} = 1V$ $V_{CC} = 15V$, $V_{O(R)} = 200mV$	12	45	-	12	45	-	-	-	-	μA	
Differential Input Voltage	$V_{I(DIFF)}$		-	-	V_{CC}	-	-	V_{CC}	-	-	V_{CC}	V	

Note :

1. $V_{CC}=30V$ for LM224 and LM324 , $V_{CC} = 26V$ for LM2902

Electrical Characteristics

($V_{CC} = 5.0V$, $V_{EE} = GND$, unless otherwise specified)

The following specifications apply over the range of $-25^{\circ}C \leq T_A \leq +85^{\circ}C$ for the LM224; and the $0^{\circ}C \leq T_A \leq +70^{\circ}C$ for the LM324; and the $-40^{\circ}C \leq T_A \leq +85^{\circ}C$ for the LM2902

Parameter	Symbol	Conditions	LM224			LM324			LM2902			Unit	
			Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.		
Input Offset Voltage	V_{IO}	$V_{ICM} = 0V$ to $V_{CC} - 1.5V$ $V_{O(P)} = 1.4V$, $R_S = 0\Omega$	-	-	7.0	-	-	9.0	-	-	10.0	mV	
Input Offset Voltage Drift	$\Delta V_{IO}/\Delta T$	-	-	7.0	-	-	7.0	-	-	7.0	-	$\mu V/^{\circ}C$	
Input Offset Current	I_{IO}	-	-	-	100	-	-	150	-	-	200	nA	
Input Offset Current Drift	$\Delta I_{IO}/\Delta T$	-	-	10	-	-	10	-	-	10	-	$pA/^{\circ}C$	
Input Bias Current	I_{BIAS}	-	-	-	300	-	-	500	-	-	500	nA	
Common-Mode Input Voltage Range	$V_{I(R)}$	Note1	0	-	$V_{CC} - 2.0$	0	-	$V_{CC} - 2.0$	0	-	$V_{CC} - 2.0$	V	
Large Signal Voltage Gain	G_V	$V_{CC} = 15V$, $R_L \geq 2.0K\Omega$ $V_{O(P)} = 1V$ to $11V$	25	-	-	15	-	-	15	-	-	V/mV	
Output Voltage Swing	$V_{O(H)}$	Note1	$R_L = 2K\Omega$	26	-	-	26	-	-	22	-	-	V
			$R_L = 10K\Omega$	27	28	-	27	28	-	23	24	-	V
	$V_{O(L)}$	$V_{CC} = 5V$, $R_L \geq 10K\Omega$	-	5	20	-	5	20	-	5	100	mV	
Output Current	I_{SOURCE}	$V_{I(+)} = 1V$, $V_{I(-)} = 0V$ $V_{CC} = 15V$, $V_{O(P)} = 2V$	10	20	-	10	20	-	10	20	-	mA	
	I_{SINK}	$V_{I(+)} = 0V$, $V_{I(-)} = 1V$ $V_{CC} = 15V$, $V_{O(P)} = 2V$	10	13	-	5	8	-	5	8	-	mA	
Differential Input Voltage	$V_{I(DIFF)}$	-	-	-	V_{CC}	-	-	V_{CC}	-	-	V_{CC}	V	

Note:

1. $V_{CC} = 30V$ for LM224 and LM324, $V_{CC} = 26V$ for LM2902

Electrical Characteristics

($V_{CC}=5.0V$, $V_{EE} = GND$, $T_A=25^\circ C$, unless otherwise specified)

Parameter	Symbol	Conditions	LM224A			LM324A			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage	V_{IO}	$V_{CM} = 0V$ to V_{CC} $-1.5V$ $V_{O(P)} = 1.4V$, $R_S = 0\ \Omega$	-	1.0	3.0	-	1.5	3.0	mV
Input Offset Current	I_{IO}	-	-	2	15	-	3.0	30	nA
Input Bias Current	I_{BIAS}	-	-	40	80	-	40	100	nA
Input Common-Mode Voltage Range	$V_{I(R)}$	$V_{CC} = 30V$	0	-	V_{CC} -1.5	0	-	V_{CC} -1.5	V
Supply Current (All Amps)	I_{CC}	$V_{CC} = 30V$	-	1.5	3	-	1.5	3	mA
		$V_{CC} = 5V$	-	0.7	1.2	-	0.7	1.2	mA
Large Signal Voltage Gain	G_V	$V_{CC} = 15V$, $R_L \geq 2\ K\Omega$ $V_{O(P)} = 1V$ to $11V$	50	100	-	25	100	-	V/mV
Output Voltage Swing	$V_{O(H)}$	Note1 $R_L = 2\ K\Omega$	26	-	-	26	-	-	V
		$R_L = 10\ K\Omega$	27	28	-	27	28	-	V
	$V_{O(L)}$	$V_{CC} = 5V$, $R_L \geq 10\ K\Omega$	-	5	20	-	5	20	mV
Common-Mode Rejection Ratio	CMRR	-	70	85	-	65	85	-	dB
Power Supply Rejection Ratio	PSRR	-	65	100	-	65	100	-	dB
Channel Separation	CS	$f = 1KHz$ to $20KHz$	-	120	-	-	120	-	dB
Short Circuit to GND	ISC	-	-	40	60	-	40	60	mA
Output Current	ISOURCE	$V_{I(+)} = 1V$, $V_{I(-)} = 0V$ $V_{CC} = 15V$	20	40	-	20	40	-	mA
	ISINK	$V_{I(+)} = 0V$, $V_{I(-)} = 1V$ $V_{CC} = 15V$, $V_{O(P)} = 2V$	10	20	-	10	20	-	mA
		$V_{I(+)} = 0V$, $V_{I(-)} = 1V$ $V_{CC} = 15V$, $V_{O(P)} = 200mV$	12	50	-	12	50	-	μA
Differential Input Voltage	$V_{I(DIFF)}$	-	-	-	V_{CC}	-	-	V_{CC}	V

Note:

1. $V_{CC}=30V$ for LM224A, LM324A

Electrical Characteristics

($V_{CC} = 5.0V$, $V_{EE} = GND$, unless otherwise specified)

The following specification apply over the range of $-25^{\circ}C \leq T_A \leq +85^{\circ}C$ for the LM224A; and the $0^{\circ}C \leq T_A \leq +70^{\circ}C$ for the LM324A

Parameter	Symbol	Conditions	LM224A			LM324A			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage	V_{IO}	$V_{CM} = 0V$ to $V_{CC} - 1.5V$ $V_{O(P)} = 1.4V$, $R_S = 0\Omega$	-	-	4.0	-	-	5.0	mV
Input Offset Voltage Drift	$\Delta V_{IO}/\Delta T$	-	-	7.0	20	-	7.0	30	$\mu V/^{\circ}C$
Input Offset Current	I_{IO}	-	-	-	30	-	-	75	nA
Input Offset Current Drift	$\Delta I_{IO}/\Delta T$	-	-	10	200	-	10	300	$pA/^{\circ}C$
Input Bias Current	I_{BIAS}	-	-	40	100	-	40	200	nA
Common-Mode Input Voltage Range	$V_{I(R)}$	$V_{CC} = 30V$	0	-	$V_{CC} - 2.0$	0	-	$V_{CC} - 2.0$	V
Large Signal Voltage Gain	G_V	$V_{CC} = 15V$, $R_L \geq 2.0K\Omega$	25	-	-	15	-	-	V/mV
Output Voltage Swing	$V_{O(H)}$	$V_{CC} = 30V$ $R_L = 2K\Omega$	26	-	-	26	-	-	V
	$V_{O(L)}$	$V_{CC} = 5V$, $R_L \geq 10K\Omega$	27	28	-	27	28	-	mV
Output Current	I_{SOURCE}	$V_{I(+)} = 1V$, $V_{I(-)} = 0V$ $V_{CC} = 15V$	10	20	-	10	20	-	mA
	I_{SINK}	$V_{I(+)} = 0V$, $V_{I(-)} = 1V$ $V_{CC} = 15V$	5	8	-	5	8	-	mA
Differential Input Voltage	$V_{I(DIFF)}$	-	-	-	V_{CC}	-	-	V_{CC}	V

Typical Performance Characteristics

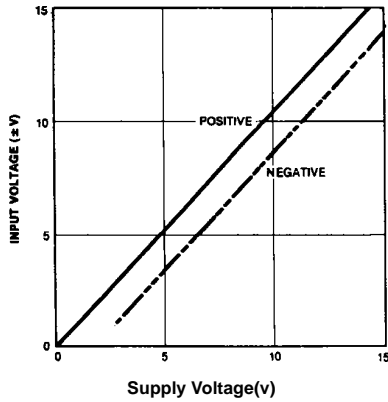


Figure 1. Input Voltage Range vs Supply Voltage

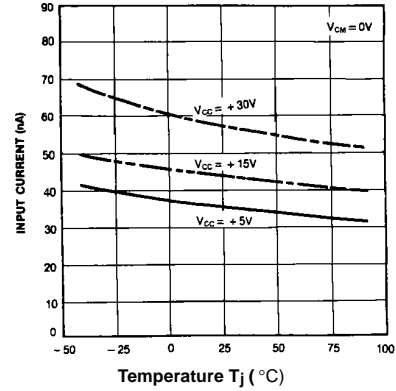


Figure 2. Input Current vs Temperature

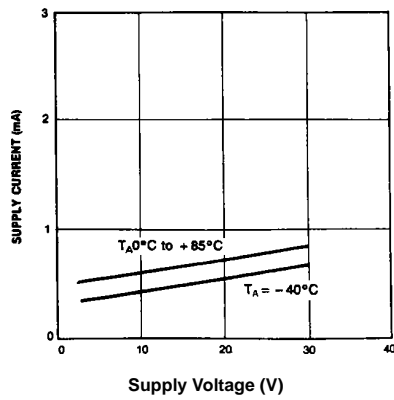


Figure 3. Supply Current vs Supply Voltage

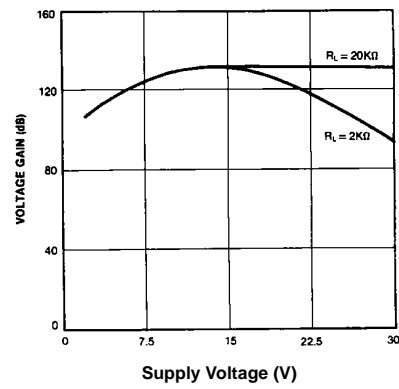


Figure 4. Voltage Gain vs Supply Voltage

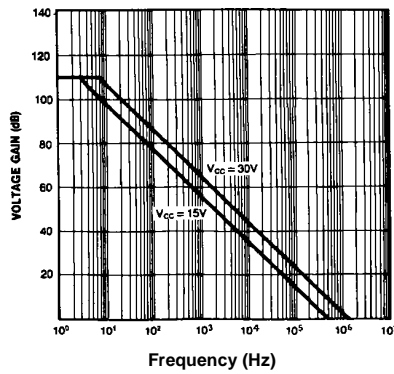


Figure 5. Open Loop Frequency Response

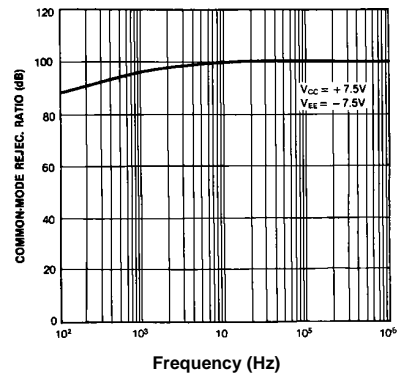


Figure 6. Common mode Rejection Ratio

Typical Performance Characteristics (continued)

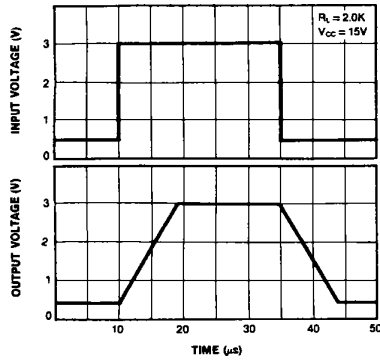


Figure 7. Slew Rate

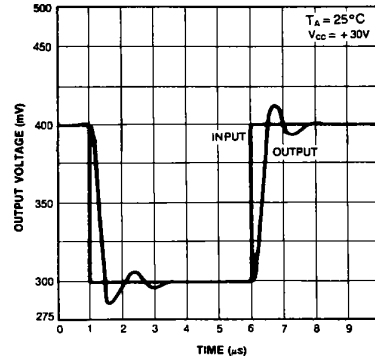


Figure 8. Voltage Follower Pulse Response

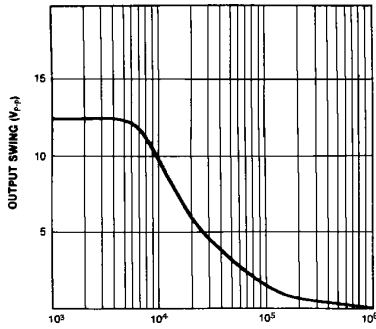


Figure 9. Large Signal Frequency Response

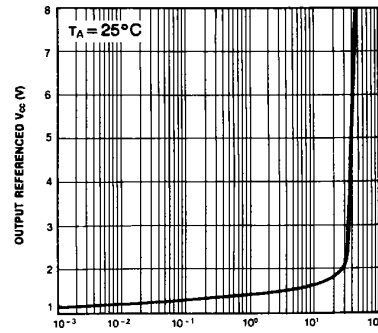


Figure 10. Output Characteristics vs Current Sourcing

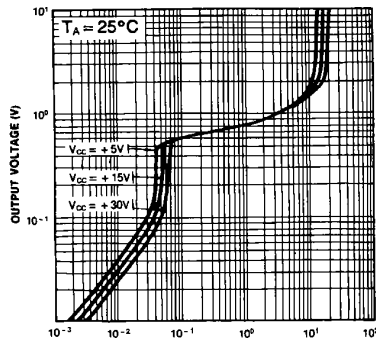


Figure 11. Output Characteristics vs Current Sinking

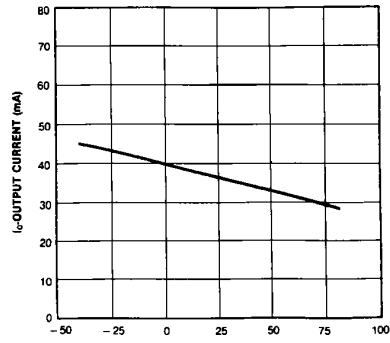
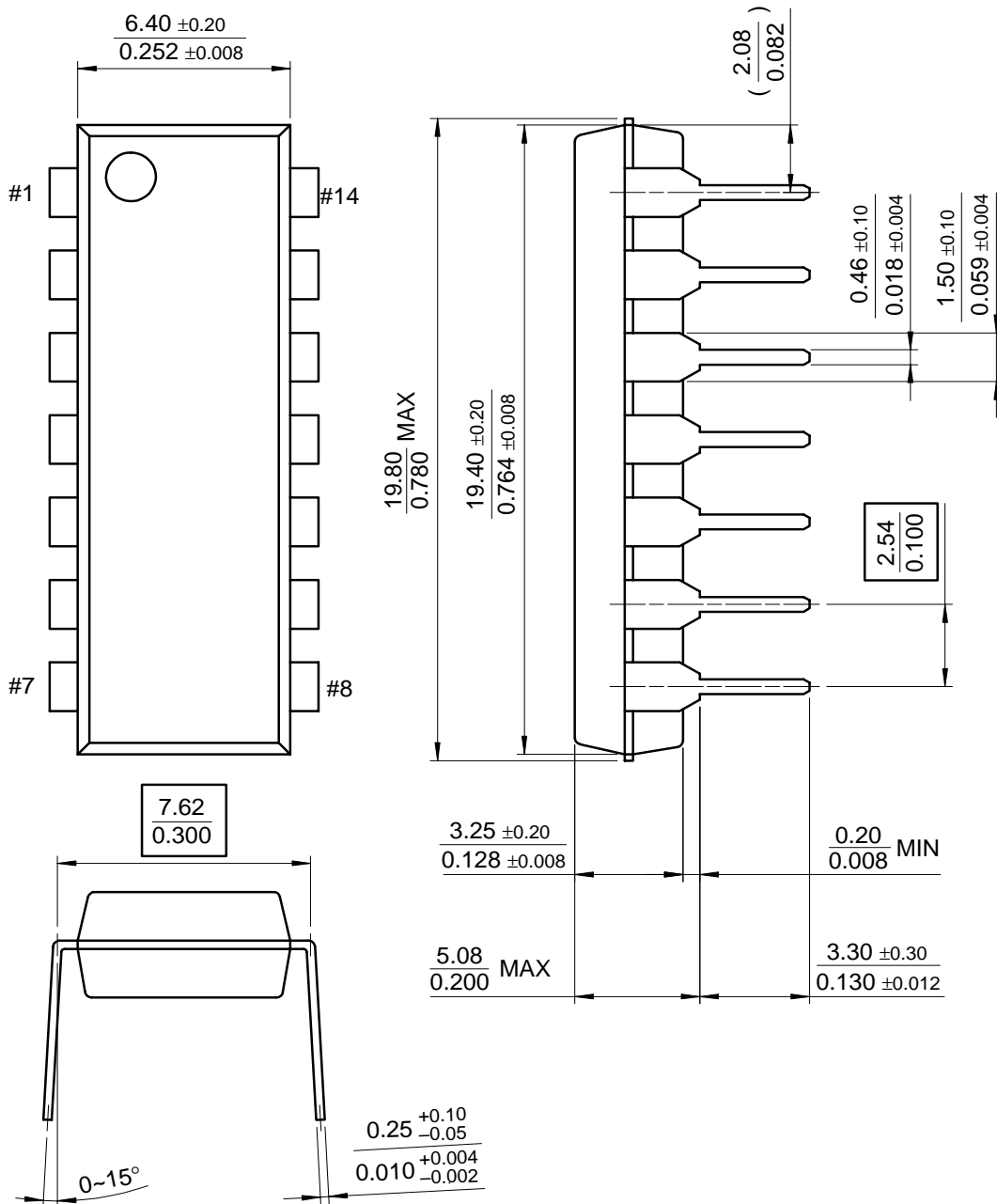


Figure 12. Current Limiting vs Temperature

Mechanical Dimensions

Package

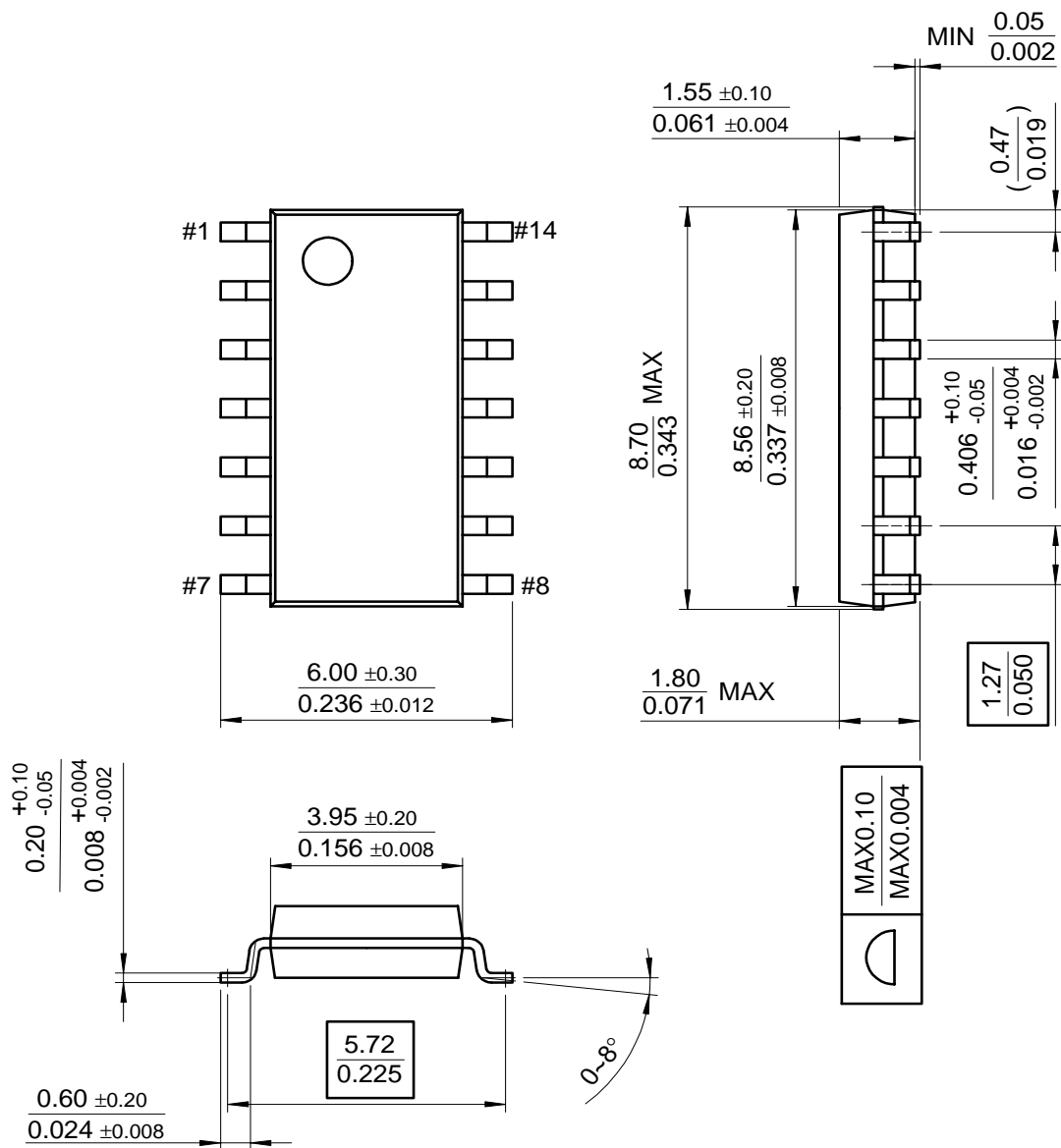
14-DIP



Mechanical Dimensions (Continued)

Package

14-SOP



Ordering Information

Product Number	Package	Operating Temperature
LM324N	14-DIP	0 ~ + 70 °C
LM324AN		
LM324M	14-SOP	
LM324AM		
LM2902N	14-DIP	-40 ~ + 85 °C
LM2902M	14-SOP	
LM224N	14-DIP	-25 ~ +85 °C
LM224AN		
LM224M	14-SOP	
LM224AM		

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